

TOSHIBA CMOS DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

TC7MZ573FK

LOW VOLTAGE OCTAL D-TYPE LATCH WITH 5 V TOLERANT INPUTS AND OUTPUTS

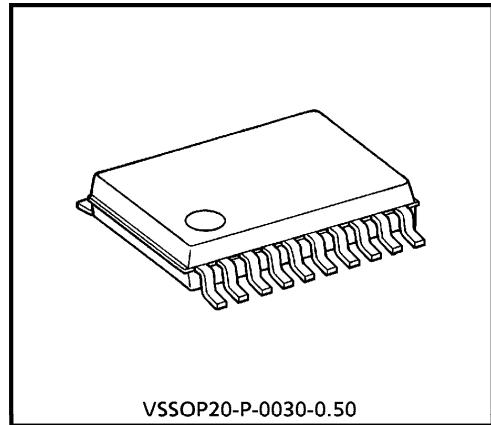
The TC7MZ573 is a high performance CMOS OCTAL D-TYPE LATCH. Designed for use in 3.3 Volt systems, it achieves high speed operation while maintaining the CMOS low power dissipation.

The device is designed for low-voltage (3.3 V) V_{CC} applications, but it could be used to interface to 5 V supply environment for both inputs and outputs.

This 8 bit D-type latch is controlled by a latch enable input (LE) and an output enable input (\overline{OE}).

When the \overline{OE} input is high, the eight outputs are in a high impedance state.

All inputs are equipped with protection circuits against static discharge.



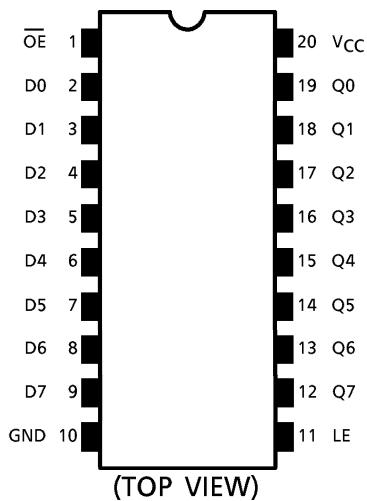
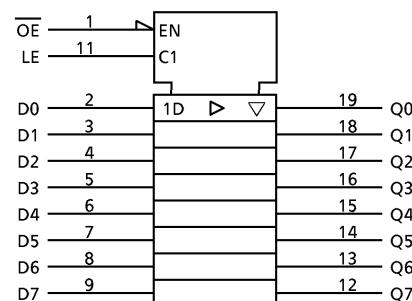
Weight : 0.03 g (typ.)

Features

- Low voltage operation : $V_{CC} = 2.0 \sim 3.6$ V
- High speed operation : $t_{pd} = 8.0$ ns (max)
($V_{CC} = 3.0 \sim 3.6$ V)
- Output current : $|I_{OH}| / |I_{OL}| = 24$ mA (min)
($V_{CC} = 3.0$ V)
- Latch-up performance : ± 500 mA
- Available in VSSOP (US20)
- Power down protection is provided on all inputs and outputs.
- Pin and function compatible with the 74 series
(74AC/VHC/HC/F/ALS/LS etc.) 573 type.

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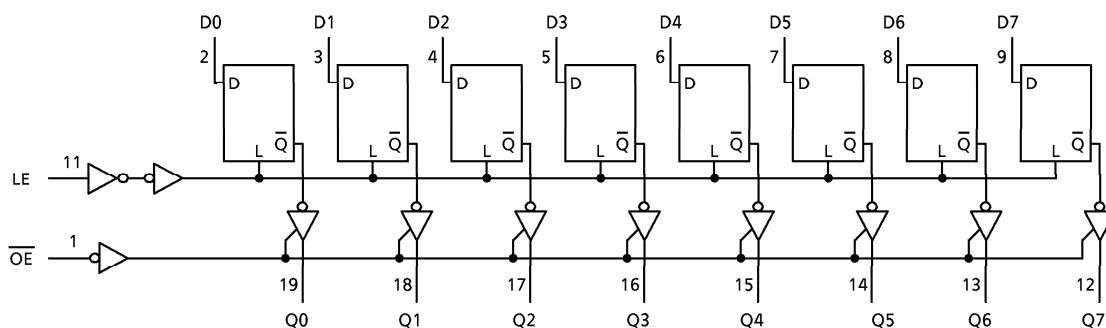
Pin Assignment**IEC Logic Symbol****Truth Table**

INPUTS			OUTPUTS
OE	LE	D	
H	X	X	Z
L	L	X	Qn
L	H	L	L
L	H	H	H

X : Don't Care

Z : High Impedance

Qn : Q outputs are latched at the time when the LE input is taken to a low logic level.

System Diagram

Maximum Ratings

PARAMETER	SYMBOL	RATING	UNIT
Supply Voltage Range	V_{CC}	-0.5~7.0	V
DC Input Voltage	V_{IN}	-0.5~7.0	V
DC Output Voltage	V_{OUT}	-0.5~7.0 (Note 1)	V
		-0.5~ V_{CC} + 0.5 (Note 2)	
Input Diode Current	I_{IK}	-50	mA
Output Diode Current	I_{OK}	± 50 (Note 3)	mA
DC Output Current	I_{OUT}	± 50	mA
Power Dissipation	P_D	180	mW
DC V_{CC} /Ground Current	I_{CC}/I_{GND}	± 100	mA
Storage Temperature	T_{stg}	-65~150	°C

(Note 1): Output in Off-State

(Note 2): High or Low State. $|I_{OUT}|$ absolute maximum rating must be observed.(Note 3): $V_{OUT} < GND$, $V_{OUT} > V_{CC}$ **Recommended Operating Conditions**

PARAMETER	SYMBOL	RATING	UNIT
Supply Voltage	V_{CC}	2.0~3.6	V
		1.5~3.6 (Note 4)	
Input Voltage	V_{IN}	0~5.5	V
Output Voltage	V_{OUT}	0~5.5 (Note 5)	V
		0~ V_{CC} (Note 6)	
Output Current	I_{OH}/I_{OL}	± 24 (Note 7)	mA
		± 12 (Note 8)	
Operating Temperature	T_{opr}	-40~85	°C
Input Rise And Fall Time	dt/dv	0~10 (Note 9)	ns/V

(Note 4): Data Retention Only

(Note 5): Output in Off-State

(Note 6): High or Low State

(Note 7): $V_{CC} = 3.0\sim 3.6$ V(Note 8): $V_{CC} = 2.7\sim 3.0$ V(Note 9): $V_{IN} = 0.8\sim 2.0$ V, $V_{CC} = 3.0$ V

Electrical CharacteristicsDC characteristics ($T_a = -40\sim85^\circ C$)

PARAMETER		SYMBOL	TEST CONDITION		V_{CC} (V)	Min	Max	UNIT	
Input Voltage	"H" Level	V_{IH}				2.7~3.6	2.0	—	
	"L" Level	V_{IL}				2.7~3.6	—	0.8	
Output Voltage	"H" Level	V_{OH}	$V_{IN} = V_{IH}$ or V_{IL}	$I_{OH} = -100 \mu A$	2.7~3.6	$V_{CC} - 0.2$	—	V	
				$I_{OH} = -12 mA$	2.7	2.2	—		
				$I_{OH} = -18 mA$	3.0	2.4	—		
				$I_{OH} = -24 mA$	3.0	2.2	—		
	"L" Level	V_{OL}	$V_{IN} = V_{IH}$ or V_{IL}	$I_{OL} = 100 \mu A$	2.7~3.6	—	0.2		
				$I_{OL} = 12 mA$	2.7	—	0.4		
				$I_{OL} = 16 mA$	3.0	—	0.4		
				$I_{OL} = 24 mA$	3.0	—	0.55		
Input Leakage Current	I_{IN}	$V_{IN} = 0\sim5.5 V$		2.7~3.6		—	± 5.0	μA	
3-State Output Off-State Current	I_{OZ}	$V_{IN} = V_{IH}$ or V_{IL} $V_{OUT} = 0\sim5.5 V$		2.7~3.6		—	± 5.0	μA	
Power Off Leakage Current	I_{OFF}	$V_{IN}/V_{OUT} = 5.5 V$		0		—	10.0	μA	
Quiescent Supply Current	I_{CC}	$V_{IN} = V_{CC}$ or GND		2.7~3.6		—	10.0	μA	
		$V_{IN}/V_{OUT} = 3.6\sim5.5 V$		2.7~3.6		—	± 10.0		
Increase In I_{CC} Per Input	ΔI_{CC}	$V_{IH} = V_{CC} - 0.6 V$		2.7~3.6		—	500	μA	

AC characteristics ($T_a = -40\sim85^\circ C$)

PARAMETER	SYMBOL	TEST CONDITION	V_{CC} (V)	Min	Max	UNIT
Propagation Delay Time (D-Q)	t_{pLH}	(Fig.1, 2)	2.7	—	9.0	ns
	t_{pHL}		3.3 ± 0.3	1.5	8.0	
Propagation Delay Time (LE-Q)	t_{pLH}	(Fig.1, 2)	2.7	—	9.5	ns
	t_{pHL}		3.3 ± 0.3	1.5	8.5	
Output Enable Time	t_{pZL}	(Fig.1, 3)	2.7	—	9.5	ns
	t_{pZH}		3.3 ± 0.3	1.5	8.5	
Output Disable Time	t_{pLZ}	(Fig.1, 3)	2.7	—	7.0	ns
	t_{pHZ}		3.3 ± 0.3	1.5	6.5	
Minimum Pulse Width (LE)	$t_w(H)$	(Fig.1, 2)	2.7	3.3	—	ns
			3.3 ± 0.3	3.3	—	
Minimum Set-Up Time	t_s	(Fig.1, 2)	2.7	2.5	—	ns
			3.3 ± 0.3	2.5	—	
Minimum Hold Time	t_h	(Fig.1, 2)	2.7	1.5	—	ns
			3.3 ± 0.3	1.5	—	
Output To Output Skew	t_{osLH}	(Note 10)	2.7	—	—	ns
	t_{osHL}		3.3 ± 0.3	—	1.0	

(Note 10): Parameter guaranteed by design.

$$(t_{osLH} = |t_{pLHm} - t_{pLHn}|, t_{osHL} = |t_{pHLm} - t_{pHLn}|)$$

Dynamic Switching Characteristics ($T_a = 25^\circ C$, Input $t_r = t_f = 2.5$ ns, $C_L = 50$ pF, $R_L = 500 \Omega$)

PARAMETER	SYMBOL	TEST CONDITION	V_{CC} (V)	Typ.	UNIT
Quiet Output Maximum Dynamic V_{OL}	V_{OLP}	$V_{IH} = 3.3$ V, $V_{IL} = 0$ V	3.3	0.8	V
Quiet Output Minimum Dynamic V_{OL}	$ V_{OLV} $	$V_{IH} = 3.3$ V, $V_{IL} = 0$ V	3.3	0.8	V

Capacitive Characteristics ($T_a = 25^\circ C$)

PARAMETER	SYMBOL	TEST CONDITION	V_{CC} (V)	Typ.	UNIT	
Input Capacitance	C_{IN}	—	3.3	7	pF	
	C_{OUT}		3.3	8	pF	
Power Dissipation Capacitance	C_{PD}	$f_{IN} = 10$ MHz	(Note 11)	3.3	25	pF

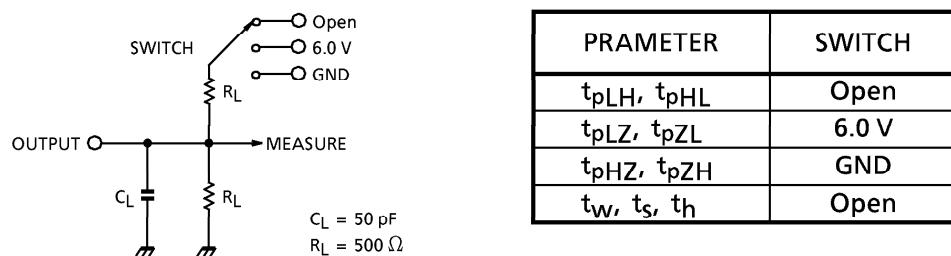
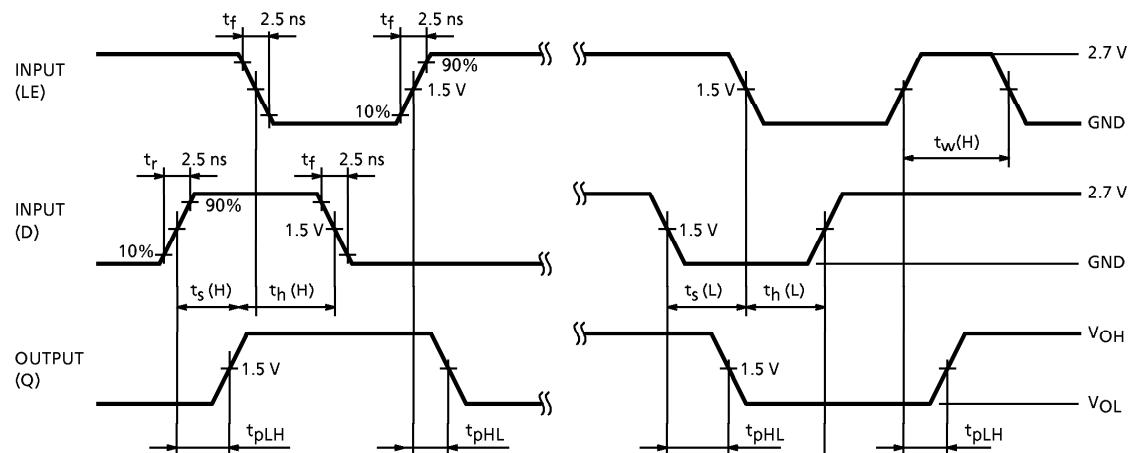
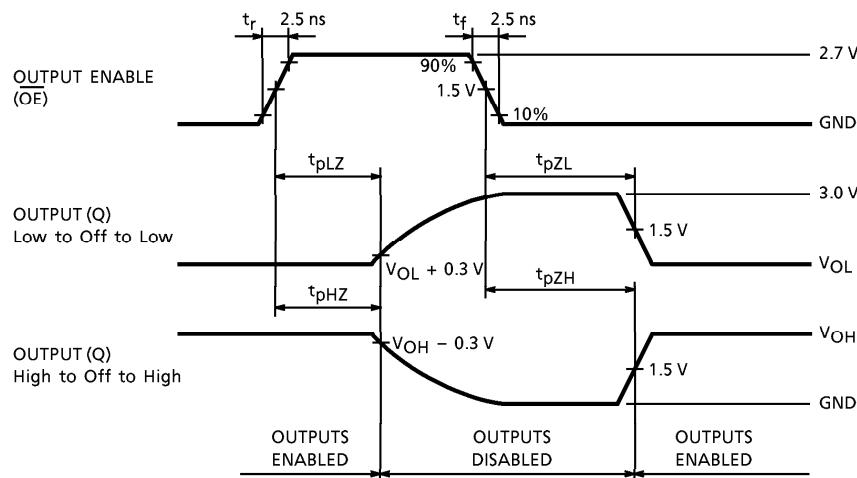
(Note 11): C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption.

Average operating current can be obtained by the equation :

$$I_{CC(\text{opr.})} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/8 \text{ (per bit)}$$

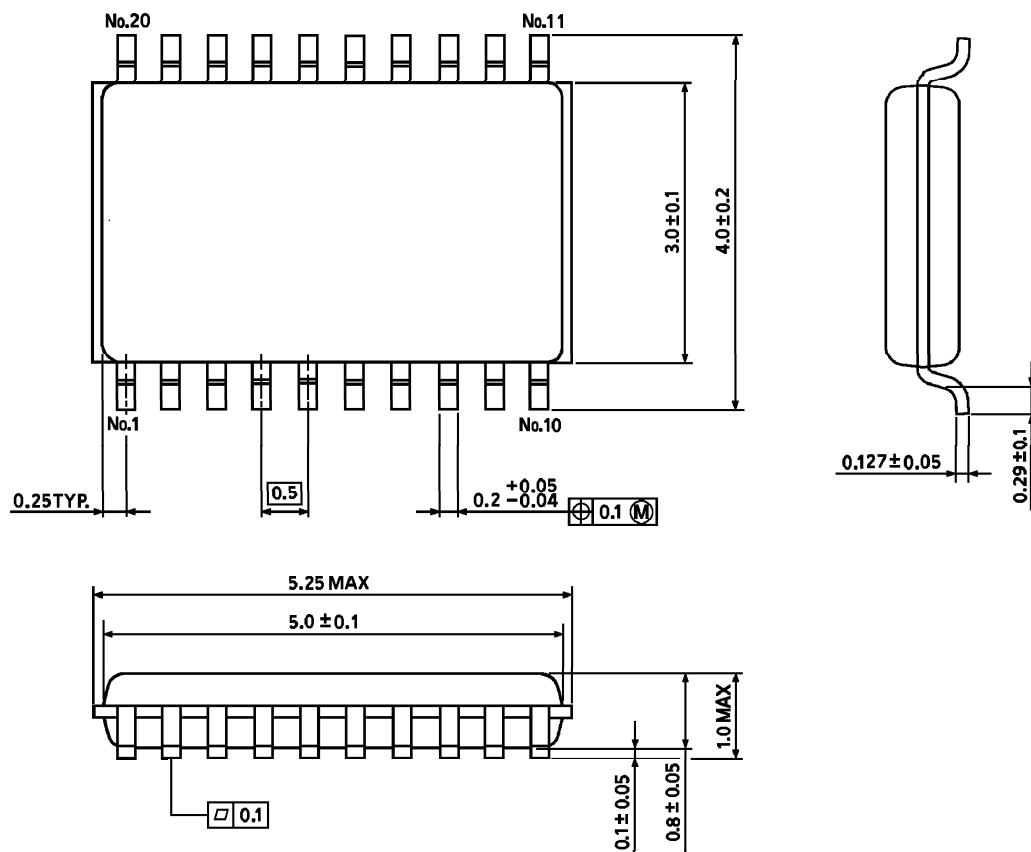
Test Circuit

Fig.1

**AC Waveform**Fig.2 $t_{pLH}, t_{pHL}, t_w, t_s, t_h$ Fig.3 $t_{pLZ}, t_{pHZ}, t_{pZL}, t_{pZH}$ 

PACKAGE DIMENSIONS
VSSOP20-P-0030-0.50

Unit : mm



Weight : 0.03 g (typ.)